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Amendments to the Claims:

This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

1-18. (canceled)

19-43. (withdrawn)

44. (new) A semiconductor device, comprising:

a semiconductor chip including an inner circuit, an input pad, and a wiring for connecting the input pad to the inner circuit;

a plurality of electrostatic protection elements connected to the wiring between the input pad and the inner circuit; and

a fuse disposed between the wiring and at least one of the electrostatic protection elements.

45. (new) The semiconductor device according to claim 1, wherein said electrostatic protection elements include a first electrostatic protection element and a second electrostatic protection element, said fuse being disposed between the wiring and the second electrostatic protection element.

46. (new) The semiconductor device according to claim 1, wherein said semiconductor chip includes a first semiconductor chip having a first wiring and a second semiconductor chip having a second wiring, said electrostatic protection elements respectively connected to the first wiring and the second wiring include a first electrostatic protection element and a second electrostatic

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protection element, and said fuse includes a first fuse and a second fuse, said first fuse being disposed between the first wiring and the second electrostatic protection element, said second fuse being disposed between the second wiring and the second electrostatic protection element so that the first fuse and second fuse are electrically disconnected.

47. (new) The semiconductor device according to claim 1, wherein said semiconductor chip includes a first semiconductor chip having a first wiring and a second semiconductor chip having a second wiring, said electrostatic protection elements respectively connected to the first wiring and the second wiring include a first electrostatic protection element and a second electrostatic protection element, and said fuse includes first fuses and second fuses, said first fuses being disposed between the first wiring and the first electrostatic protection element and between the second wiring and the first electrostatic protection element, said second fuses being disposed between the first wiring and the second electrostatic protection element and the second wiring and the second electrostatic protection element so that at least ones of said first fuses and said second fuses being electrically disconnected.

48. (new) The semiconductor device according to claim 1, wherein said semiconductor chip includes semiconductor chips in a number of n each having the wiring wherein n is an integer more than 3; said electrostatic protection elements respectively connected to the wirings includes first to n -th electrostatic protection elements; and said fuse includes second to n -th fuses respectively disposed between the wirings and the second to n -th electrostatic protection

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elements so that the second to n-th fuses are electrically disconnected.

49. (new) The semiconductor device according to claim 1, wherein said semiconductor chip includes semiconductor chips in a number of n each having the wiring wherein n is an integer more than 3; said electrostatic protection elements respectively connected to the wirings includes first to n-th electrostatic protection elements; and said fuse includes first to n-th fuses respectively disposed between the wirings and the first to n-th electrostatic protection elements so that at least one of the first to n-th fuses being electrically connected.

50. (new) The semiconductor device according to claim 1, wherein said semiconductor chip includes semiconductor chips in a number of n each having the wiring wherein n is an integer more than 3; said electrostatic protection elements respectively connected to the wirings includes first to n-th electrostatic protection elements; and said fuse includes first to n-th fuses respectively disposed between the wirings and the first to n-th electrostatic protection elements so that at least two of the first to n-th fuses are electrically connected.

51. (new) The semiconductor device according to claim 1, wherein said semiconductor chip includes semiconductor chips in a number of o or p each having the wiring wherein o and p are integers more than 2; said electrostatic protection elements respectively connected to the wirings includes a first to m-th electrostatic protection elements wherein m is a lowest common multiple of o and p; and said fuse includes second to m-th fuses respectively disposed between the wirings and the second to m-th electrostatic

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protection elements so that the $(m/o + 1)$ -th to m -th fuses are electrically disconnected when the semiconductor chips are in the number of o , and the $(m/p + 1)$ -th to m -th fuses are electrically disconnected when the semiconductor chips are in the number of p .

52. (new) The semiconductor device according to claim 1, wherein said semiconductor chip includes semiconductor chips in a number of o or p each having the wiring wherein o and p are integers more than 2; said electrostatic protection elements respectively connected to the wirings includes a first to m -th electrostatic protection elements wherein m is a lowest common multiple of o and p ; and said fuse includes first to m -th fuses respectively disposed between the wirings and the first to m -th electrostatic protection elements so that the $(m/o + 1)$ -th to m -th fuses are electrically disconnected when the semiconductor chips are in the number of o , and the $(m/p + 1)$ -th to m -th fuses are electrically disconnected when the semiconductor chips are in the number of p .